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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# 1-Mbit (64K x 16) Static RAM

#### **Features**

· Temperature Ranges

— Commercial: 0°C to 70°C

— Industrial: –40°C to 85°C

- Automotive-A: -40°C to 85°C

— Automotive-E: –40°C to 125°C

· High speed

- t<sub>AA</sub> = 10 ns (Commercial)

 $-t_{AA} = 15 \text{ ns (Automotive)}$ 

CMOS for optimum speed/power

· Low active power

- 825 mW (max.)

Automatic power-down when deselected

· Independent control of upper and lower bits

 Available in Pb free and non Pb free 44-pin TSOP II and 44-pin 400-mil-wide SOJ

#### Functional Description[1]

The CY7C1021BN/CY7C10211BN is a high-performance CMOS static RAM organized as 65,536 words by 16 bits. This device has an automatic power-down feature that significantly reduces power consumption when deselected.

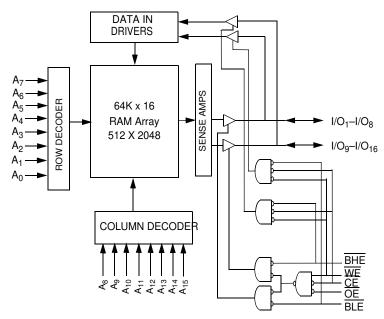
Writing to the device is accomplished by taking Chip Enable ( $\overline{\text{CE}}$ ) and Write Enable (WE) inputs LOW. If Byte Low Enable (BLE) is LOW, then data from I/O pins (I/O<sub>1</sub> through I/O<sub>8</sub>), is written into the location specified on the address pins (A<sub>0</sub> through A<sub>15</sub>). If Byte High Enable (BHE) is LOW, then data from I/O pins (I/O<sub>9</sub> through I/O<sub>16</sub>) is written into the location specified on the address pins (A<sub>0</sub> through A<sub>15</sub>).

Reading from the device is accomp lished by taking Chip Enable (CE) and Output Enable (OE) LOW while forcing the Write Enable (WE) HIGH. If Byte Low Enable (BLE) is LOW, then data from the memory location specified by the address pins will appear on I/O<sub>1</sub> to I/O<sub>8</sub>. If Byte High Enable (BHE) is LOW, then data from memory will appear on I/O<sub>9</sub> to I/O<sub>16</sub>. See the truth table at the back of this data sheet for a complete description of read and write modes.

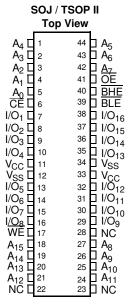
The input/output pins (I/O<sub>1</sub> through I/O<sub>16</sub>) are placed in a high-impedance state when the device is deselected (CE HIGH), the outputs are disabled (OE HIGH), the BHE and BLE are disabled (BHE, BLE HIGH), or during a write operation (CE LOW, and  $\overline{\text{WE}}$  LOW).

The CY7C1021BN/CY7C10211BN is available in standard 44-pin TSOP Type II and 44-pin 400-mil-wide SOJ packages. Customers should use part number CY7C10211BN when ordering parts with 10 ns  $t_{AA}$ , and CY7C1021BN when ordering 12 ns and 15 ns  $t_{AA}$ .

#### **Logic Block Diagram**



# **PirConfigurations**



#### Note:

1. For best-practice recommendations, please refer to the Cypress application note "System Design Guidelines" on http://www.cypress.com



### **Selection Guide**

		7C10211B-10	7C1021B-12	7C1021B-15
Maximum Access Time (ns)		10	12	15
Maximum Operating Current (mA) Com'l / Ind'l		150	140	130
	Automotive-A			130
	Automotive-E			130
Maximum CMOS Standby Current (mA)	Com'l / Ind'l	10	10	10
	Com'l / Ind'l (L version)	0.5	0.5	0.5
	Automotive-A (L version)			0.5
	Automotive-E			15

## **Pin Definitions**

Pin Name	SOJ, TSOP-Pin Number	I/O Type	Description
A <sub>0</sub> -A <sub>15</sub>	1-5,18-21, 24-27, 42-44	Input	Address Inputs used to select one of the address locations.
I/O <sub>1</sub> –I/O <sub>16</sub>	7–10, 13–16, 29–32, 35–38	Input/Output	<b>Bidirectional Data I/O lines</b> . Used as input or output lines depending on operation.
NC	22, 23, 28	No Connect	No Connects. Not connected to the die.
WE	17	Input/Control	Write Enable Input, active LOW. When selected LOW, a Write is conducted. When deselected HIGH, a Read is conducted.
CE	6	Input/Control	Chip Enable Input, active LOW. When LOW, selects the chip. When HIGH, deselects the chip.
BHE, BLE	40, 39	Input/Control	
ŌĒ	41	Input/Control	Output Enable, active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins are allowed to behave as outputs. When deasserted HIGH, I/O pins are tri-stated, and act as input data pins.
V <sub>SS</sub>	12, 34	Ground	<b>Ground for the device</b> . Should be connected to ground of the system.
V <sub>CC</sub>	11, 33	Power Supply	Power Supply inputs to the device.



#### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.) Storage Temperature .....-65°C to +150°C Ambient Temperature with Power Applied ......55°C to +125°C Supply Voltage on  $V_{CC}$  Relative to  $GND^{[2]}$  .... –0.5V to +7.0V DC Voltage Applied to Outputs in High Z State  $^{[2]}$  .....-0.5V to  $V_{CC}$ +0.5V DC Input Voltage<sup>[2]</sup>.....-0.5V to V<sub>CC</sub>+0.5V Current into Outputs (LOW) ......20 mA

Static Discharge Voltage	>2001V
(per MIL-STD-883, Method 3015)	
Latch-Up Current	>200 mA

#### **Operating Range**

Range	Ambient Temperature (T <sub>A</sub> ) <sup>[3]</sup>	V <sub>cc</sub>
Commercial	0°C to +70°C	5V ± 10%
Industrial	-40°C to +85°C	
Automotive-A	–40°C to +85°C	
Automotive-E	–40°C to +125°C	

#### **Electrical Characteristics** Over the Operating Range

		Test		-1	10	-12		-15		
Parameter	Description		litions	Min.	Max.	Min.	Max.	Min.	Max.	Unit
V <sub>OH</sub>	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -$	–4.0 mA	2.4		2.4		2.4		V
V <sub>OL</sub>	Output LOW Voltage	$V_{CC} = Min., I_{OL} = 8$	3.0 mA		0.4		0.4		0.4	V
V <sub>IH</sub>	Input HIGH Voltage			2.2	6.0	2.2	6.0	2.2	6.0	V
V <sub>IL</sub>	Input LOW Voltage <sup>[2]</sup>			-0.5	0.8	-0.5	0.8	-0.5	0.8	V
I <sub>IX</sub>	Input Leakage	$GND \le V_1 \le V_{CC}$	Com'l / Ind'l	-1	+1	-1	+1	-1	+1	μА
	Current		Automotive-A					-1	+1	μА
			Automotive-E					-4	+4	μА
l <sub>OZ</sub>		kage $GND \le V_1 \le V_{CC}$ , Output Disabled	Com'l / Ind'l	-1	+1	-1	+1	-1	+1	μА
	Current		Automotive-A					-1	+1	μА
			Automotive-E					-4	+4	μА
I <sub>CC</sub>	V <sub>CC</sub> Operating	V <sub>CC</sub> = Max.,	Com'l / Ind'l		150		140		130	mA
	Supply Current	$I_{OUT} = 0 \text{ mA},$ $f = f_{MAX} = 1/t_{RC}$	Automotive-A						130	
		I WAX "TO	Automotive-E						130	
I <sub>SB1</sub>	Automatic CE	Max. V <sub>CC</sub> ,	Com'l / Ind'l		40		40		40	mA
	Power-Down Current—TTL	$\overline{CE} \ge V_{IH}$ $V_{IN} \ge V_{IH}$ or	Automotive-A						40	
	Inputs	$V_{IN} \le V_{IL}$ , $f = f_{MAX}$	Automotive-E						50	
I <sub>SB2</sub>	Automatic CE	Max. V <sub>CC</sub> ,	Com'l / Ind'l		10		10		10	mA
	Power-Down Current—	$\overline{CE} \ge V_{CC} - 0.3V,$ $V_{IN} \ge V_{CC} - 0.3V,$	Com'l / Ind'l (L)		0.5		0.5		0.5	
	CMOS Inputs	or $V_{IN} \le v_{CC} - 0.3v$ , $f = 0$	Automotive-A (L)						0.5	
			Automotive-E						15	

### Capacitance<sup>[4]</sup>

Parameter	Description	Test Conditions	Max.	Unit
C <sub>IN</sub>	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	8	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.0V$	8	pF

#### Notes:

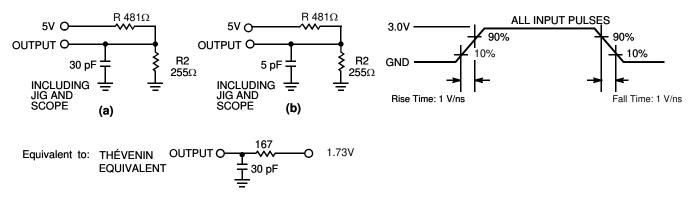
<sup>2.</sup> V<sub>IL</sub> (min.) = -2.0V and V<sub>IH</sub>(max) = V<sub>CC</sub> + 0.5V for pulse durations of less than 20 ns.
3. T<sub>A</sub> is the "Instant On" case temperature.
4. Tested initially and after any design or process changes that may affect these parameters.



## Thermal Resistance<sup>[4]</sup>

Parameter	Description	Test Conditions	44-pin SOJ	44-pin TSOP-II	Unit
$\Theta_{JA}$	(Junction to Ambient)	and procedures for measuring thermal	64.32	76.89	°C/W
$\Theta_{\sf JC}$	Thermal Resistance (Junction to Case)	impedance, per EIA / JESD51.	31.03	14.28	°C/W

#### **AC Test Loads and Waveforms**



### Switching Characteristics<sup>[5]</sup> Over the Operating Range

		7C102	11B-10	7C102	21B-12	7C102	21B-15	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
Read Cycle		•	•	•	•	•	•	
t <sub>RC</sub>	Read Cycle Time	10		12		15		ns
t <sub>AA</sub>	Address to Data Valid		10		12		15	ns
t <sub>OHA</sub>	Data Hold from Address Change	3		3		3		ns
t <sub>ACE</sub>	CE LOW to Data Valid		10		12		15	ns
t <sub>DOE</sub>	OE LOW to Data Valid		5		6		7	ns
t <sub>LZOE</sub>	OE LOW to Low Z <sup>[6]</sup>	0		0		0		ns
t <sub>HZOE</sub>	OE HIGH to High Z <sup>[6, 7]</sup>		5		6		7	ns
t <sub>LZCE</sub>	CE LOW to Low Z <sup>[6]</sup>	3		3		3		ns
t <sub>HZCE</sub>	CE HIGH to High Z <sup>[6, 7]</sup>		5		6		7	ns
t <sub>PU</sub>	CE LOW to Power-Up	0		0		0		ns
t <sub>PD</sub>	CE HIGH to Power-Down		10		12		15	ns
t <sub>DBE</sub> Byte Enable to Data Valid			5		6		7	ns
t <sub>LZBE</sub>	Byte Enable to Low Z	0		0		0		ns
t <sub>HZBE</sub>	Byte Disable to High Z		5		6		7	ns

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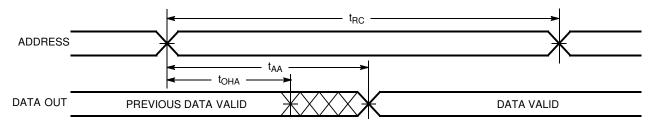


## **Switching Characteristics**<sup>[5]</sup> Over the Operating Range (continued)

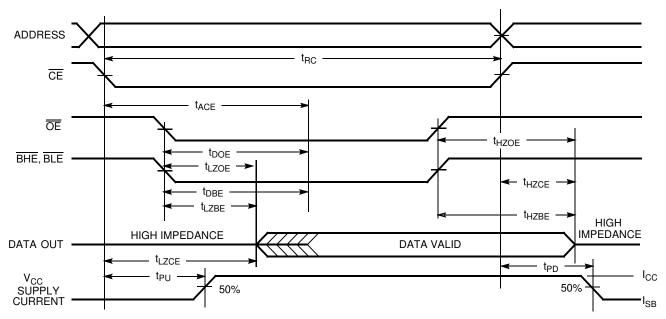
		7C102	11B-10	7C102	21B-12	7C102	21B-15	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
Write Cycle <sup>[8]</sup>		•	•	•	•	•	•	•
t <sub>WC</sub>	Write Cycle Time	10		12		15		ns
t <sub>SCE</sub>	CE LOW to Write End	8		9		10		ns
t <sub>AW</sub>	Address Set-Up to Write End	7		8		10		ns
t <sub>HA</sub>	Address Hold from Write End	0		0		0		ns
t <sub>SA</sub>	Address Set-Up to Write Start	0		0		0		ns
t <sub>SD</sub>	Data Set-Up to Write End	5		6		8		ns
t <sub>HD</sub>	Data Hold from Write End	0		0		0		ns
t <sub>LZWE</sub>	WE HIGH to Low Z <sup>[6]</sup>	3		3		3		ns
t <sub>HZWE</sub>	WE LOW to High Z <sup>[6, 7]</sup>		5		6		7	ns
t <sub>BW</sub>	Byte Enable to End of Write	7		8		9		ns

### **Switching Waveforms**

Read Cycle No. 1<sup>[9, 10]</sup>



# Read Cycle No. 2 (OE Controlled)[10, 11]

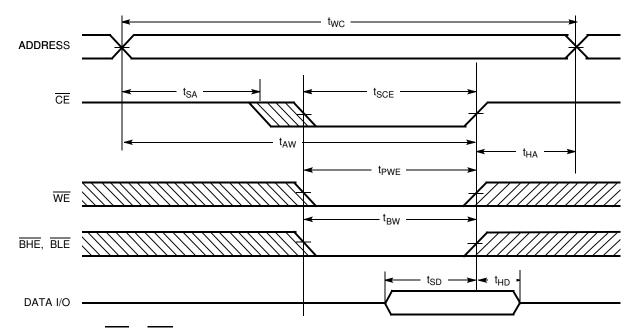


- 8. The internal write time of the memory is defined by the overlap of CE LOW, WE LOW and BHE / BLE LOW. CE, WE and BHE / BLE must be LOW to initiate a write, and the transition of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.
- 9. Device is continuously selected.  $\overline{OE}$ ,  $\overline{CE}$ ,  $\overline{BHE}$  and/or  $\overline{BHE}$  =  $V_{IL}$ . 10.  $\overline{WE}$  is HIGH for read cycle.

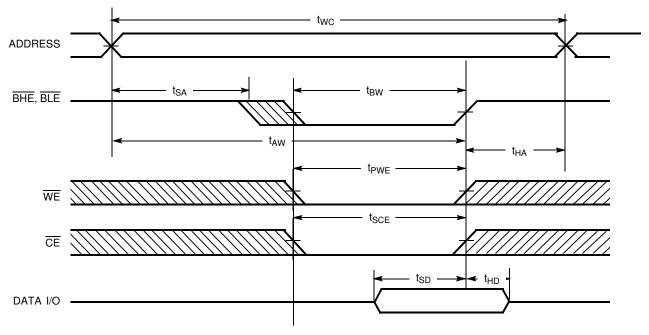


## Switching Waveforms (continued)

Write Cycle No. 1 (CE Controlled)[12, 13]



# Write Cycle No. 2 (BLE or BHE Controlled)



- Notes:

  11. Address valid prior to or coincident with CE transition LOW.

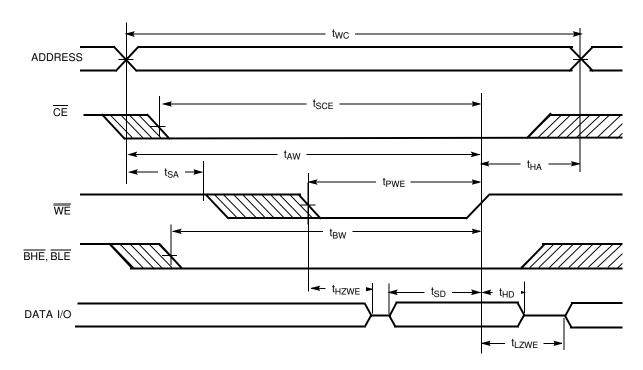
  12. Data I/O is high impedance if OE or BHE and/or BLE= V<sub>IH</sub>.

  13. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high-impedance state.



# Switching Waveforms (continued)

# Write Cycle No. 3 (WE Controlled, OE LOW)



### **Truth Table**

CE	OE	WE	BLE	BHE	I/O <sub>1</sub> –I/O <sub>8</sub>	I/O <sub>9</sub> –I/O <sub>16</sub>	Mode	Power
Н	Х	Х	Χ	Х	High Z	High Z	Power-Down	Standby (I <sub>SB</sub> )
L	L	Н	L	L	Data Out	Data Out	Read - All bits	Active (I <sub>CC</sub> )
			L	Н	Data Out	High Z	Read - Lower bits only	Active (I <sub>CC</sub> )
			Н	L	High Z	Data Out	Read - Upper bits only	Active (I <sub>CC</sub> )
L	Х	L	L	L	Data In	Data In	Write - All bits	Active (I <sub>CC</sub> )
			L	Н	Data In	High Z	Write - Lower bits only	Active (I <sub>CC</sub> )
			Н	L	High Z	Data In	Write - Upper bits only	Active (I <sub>CC</sub> )
L	Н	Н	Х	Х	High Z			Active (I <sub>CC</sub> )
L	Х	Х	Н	Н	High Z	High Z	Selected, Outputs Disabled	Active (I <sub>CC</sub> )

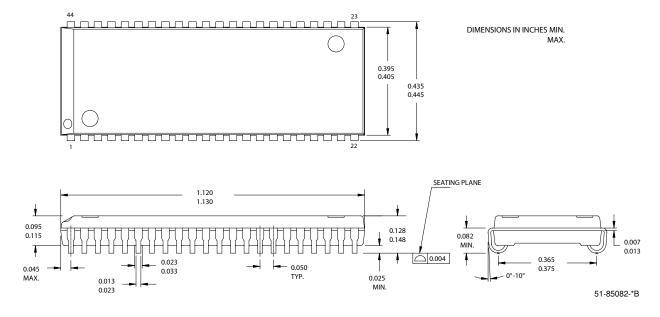


#### **Ordering Information**

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C10211BN-10ZXC	51-85087	44-pin TSOP Type II	Commercial
12	CY7C1021BN-12VC	51-85082	44-pin (400-Mil) Molded SOJ	Commercial
	CY7C1021BN-12VXC		44-pin (400-Mil) Molded SOJ (Pb-Free)	
	CY7C1021BN-12ZC	51-85087	44-pin TSOP Type II	
	CY7C1021BN-12ZXC		44-pin TSOP Type II (Pb-Free)	
	CY7C1021BN-12VI	51-85082	44-pin (400-Mil) Molded SOJ	Industrial
	CY7C1021BN-12VXI		44-pin (400-Mil) Molded SOJ (Pb-Free)	
15	CY7C1021BN-15VC	51-85082	44-pin (400-Mil) Molded SOJ	Commercial
	CY7C1021BN-15VXC		44-pin (400-Mil) Molded SOJ (Pb-Free)	
	CY7C1021BNL-15VXC		44-pin (400-Mil) Molded SOJ (Pb-Free)	
	CY7C1021BN-15ZC	51-85087	44-pin TSOP Type II	
	CY7C1021BN-15ZXC		44-pin TSOP Type II (Pb-Free)	
	CY7C1021BNL-15ZC		44-pin TSOP Type II	
	CY7C1021BNL-15ZXC		44-pin TSOP Type II (Pb-Free)	
	CY7C1021BN-15VI	51-85082	44-pin (400-Mil) Molded SOJ	Industrial
	CY7C1021BN-15VXI		44-pin (400-Mil) Molded SOJ (Pb-Free)	
	CY7C1021BN-15ZI	51-85087	44-pin TSOP Type II	
	CY7C1021BNL-15ZI		44-pin TSOP Type II	
	CY7C1021BN-15ZXI		44-pin TSOP Type II (Pb-Free)	
	CY7C1021BNL-15ZXI		44-pin TSOP Type II (Pb-Free)	
	CY7C1021BNL-15ZSXA	51-85087	44-pin TSOP Type II (Pb-Free)	Automotive-A
	CY7C1021BN-15VXE	51-85082	44-pin (400-Mil) Molded SOJ (Pb-Free)	Automotive-E
	CY7C1021BN-15ZSXE	51-85087	44-pin TSOP Type II (Pb-Free)	

# **Package Diagrams**

### 44-pin (400-Mil) Molded SOJ (51-85082)

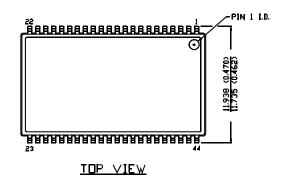


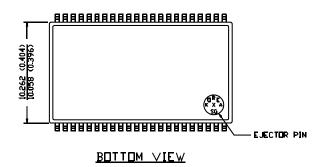


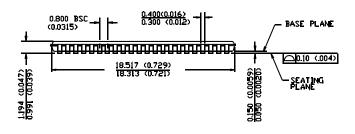
#### Package Diagrams (continued)

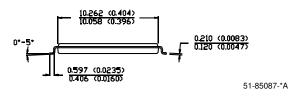
#### 44-Pin TSOP II (51-85087)

DIMENSION IN MM (INCH)
MAX
NIN.









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# **Document History Page**

	Document Title: CY7C1021BN/CY7C10211BN (64K x 16) Static RAM Document Number: 001-06494								
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change					
**	423877	See ECN	NXR	New Data Sheet					
*A	505726 See ECN NXR Removed I <sub>OS</sub> parameter from DC Electrical Characteristics table. Added Automotive products Updated ordering Information table								